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Declaration and Power of Attorney For Patent Application 特許出願宣言書及び委任状

Japanese Language Declaration 日本語宜言書

下記の氏名の発明者として、私は以下の通り宣言します。	As a below named inventor, I hereby declare that:
私の住所、私書箱、国籍は下記の私の氏名の後に記載された通りです。	My residence, post office address and citizenship are as stated next to my name.
下記の名称の発明に関して請求範囲に記載され、特許出願している発明内容について、私が最初かつ唯一の発明者(下記の氏名が一つの場合)もしくは最初かつ共同発明者であると(下記の名称が複数の場合)信じています。	I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled
	SEMICONDUCTOR DEVICE HAVING ALUMINUM NITRIDE FILM
上記発明の明細書(下記の欄で×印がついていない場合は、本書に添付)は、	The specification of which is attached hereto unless the following box is checked:
□月日に提出され、米国出願番号または特許協定条約 国際出願番号を とし、(該当する場合)に訂正されました。	was filed on April 22, 1999 as United States Application Number or PCT International Application Number 09/295,607and was amended on April 22, 1999, January 4, 2000 and August 3, 2000 (if applicable).
私は、特許請求範囲を含む上記訂正後の明細書を検討し、 内容を理解していることをここに表明します。	I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information which is

material to patentability as defined in Title 37, Code of

Federal Regulations, Section 1.56.

私は、連邦規則法典第37編第1条56項に定義されるとお

り、特許資格の有無について重要な情報を開示する義務があ

ることを認めます。

Japanese Language Declaration (日本語宜言書)

私は、米国法典第 35 編 119 条(a)·(d)項又は 365 条(b)項 に基き下記の、米国以外の国の少なくとも一カ国を指定している特許協力条約 365(a)項に基く国際出願、又は外国での特許出願もしくは発明者証の出願についての外国優先権をここに主張するとともに、優先権を主張している、本出願の前に出願された特許または発明者証の外国出願を以下に、枠内をマークすることで、示しています。

I hereby claim foreign priority under Title 35, United States Code, Section 119(a)-(d) or 365(b) of any foreign application(s) for patent or inventor's certificate, or 365(a) of any PCT International application which designated at least one country other than the United States, listed below and have also identified below, by checking the box, any foreign application for patent or inventor's certificate, or PCT International application having a filing date before that of the application on which priority is claimed.

(現況: 特許許可済、継続中、放棄済)

Prior Foreign Application(s) 外国での先行出願			Priority Not Claimed 優先権主張なし
4-201932	Japan	July 6, 1992	
(Number)	(Country)	(Day/Month/Year Filed)	_
(番号)	(国名)	(出願年月日)	
4-218324	Japan	July 24, 1992	
(Number)	(Country)		
(番号)	(国名)	(Day/Month/Year Filed) (出願年月日)	· ,
5-45786	Japan	February 10, 1993	
(Number)	(Country)	(Day/Month/Year Filed)	
(番号)	(国名)	(出願年月日)	
私は、第35編米国法典 119条(e)項 許出願規定に記載された権利をここに		I hereby claim the benefit unde Code, Section 119(e) of any U application(s) listed below.	
(Application No.)	(Filing Date)	(Application No.)	(Filing Date)
(出願番号)	(出願日)	(出願番号)	(出願日)
私は、下記の米国法典第35編120 特許出願に記載された権利、又は米協力条約365条(c)に基く権利をここ 出願の各請求範囲の内容が米国法典 又は特許協力条約で規定された方法 願に開示されていない限り、その先行 で本出願書の日本国内または特許協の期間中に入手された、連邦規制法典 定義された特許資格の有無に関する 記義務があることを認識しています。	国を指定している特許 に主張します。また、本 代35編112条第1項 で先行する米国特許出 牙米国出願提出日以降 力条約国際提出日まで 東第37編1条56項で	I hereby claim the benefit under Code, Section 120 of any United 365(c) of any PCT International the United States, listed below ar matter of each of the claims of disclosed in the prior United States application in the manner provide of Title 35, United States acknowledge the duty to disclosed material to patentability as defin Federal Regulations, Section available between the filing date and the national or PCT Integraphication.	States application(s), or application designating and, insofar as the subject of this application is not tes or PCT International and by the first paragraph Code Section 112, I se information which is ned in Title 37, Code of 1.56 which became of the prior application
08/085,931 (Application No.)	<u>July 6, 1993</u> (Filing Date)	Abandoned (Status: Patented, Pendi	ng Abandoned)

(出願日)

(出願番号)

08/757,616 (Application No.) (出願番号)	November 29, 1996 (Filing Date) (出願日)	Patented (USP5,946,561) (Status: Patented, Pending, Abandoned) (現況: 特許許可済、継続中、放棄済)
	February 23, 1999 (Filing Date) (出願日)	Pending (Status: Patented, Pending, Abandoned) (現況: 特許許可済、継続中、放棄済)
(Application No.)	(Filing Date)	(Status: Patented, Pending, Abandoned)
(出願番号)	(出願日)	(現況: 特許許可済、継続中、放棄済)
(Application No.)	(Filing Date)	(Status: Patented, Pending, Abandoned)
(出願番号)	(出願日)	(現況: 特許許可済、継続中、放棄済)
(Application No.)	(Filing Date)	(Status: Patented, Pending, Abandoned)
(出願番号)	(出願日)	(現況: 特許許可済、継続中、放棄済)
(Application No.)	(Filing Date)	(Status: Patented, Pending, Abandoned)
(出願番号)	(出願日)	(現況: 特許許可済、継続中、放棄済)
(Application No.)	(Filing Date)	(Status: Patented, Pending, Abandoned)
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私は、私自身の知識に基いて本宣言書中で私が行う表明が真実であり、かつ私の入手した情報と私の信じるところに基く表明が全て真実であると信じていること、さらに故意になされた虚偽の表明及びそれと同等の行為は米国法典第 18 編第1001 条に基き、罰金または拘禁、もしくはその両方により処罰されること、そしてそのような故意による虚偽の声明を行えば、出願した、又は既に許可された特許の有効性が失われることを認識し、よってここに上記のごとく宣誓を致します。

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Japanese Language Declaration (日本語宜言書)

委任状: 私は下記の発明者として、本出願に関する一切の手続きを米特許商標局に対して遂行する弁護士または代理人として、下記の者を指名いたします。 (弁護士、または代理人の氏名及び登録番号を明記のこと)

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POWER OF ATTORNEY: As a named inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith (list name and registration number).

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The undersigned hereby authorizes any U. S. attorney or agent named herein to accept and follow instructions from ______ as to any action to be taken in the Patent and Trademark Office regarding this application without direct communication between the U. S. attorney or agent and the undersigned. In the event of a change in the persons from whom instructions may be taken, the U. S. attorneys or agents named herein will be so notified by the undersigned.

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